NSN 5961-01-047-1756

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-047-1756 **Inclosure Material:** Ceramic **Overall Length:** 0.840 inches **Overall Height:** 0.120 inches **Overall Width:** Between 0.220 inches and 0.310 inches **Component Name And Quantity:** 7 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open all transistor and 16.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor and 100.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Common emitter; transistors junction pattern arrangement: npn **Terminal Type And Quantity:** 16 printed circuit **Specification Data:** 34371-ca3081f manufacturers specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No